

## 2 $\mu\text{m}$ Ho:YAG and Cr:ZnSe Thin Disk cw Lasers

G. Renz, J. Speiser, and A. Giesen

Institute of Technical Physics, German Aerospace Center, Pfaffenwaldring 38  
70569 Stuttgart, Germany  
e-mail: [G.Renz@dlr.de](mailto:G.Renz@dlr.de)

### Summary

A Thulium fiber laser pumped Ho:YAG thin disk cw laser with an output power of 15 W at a 2% Ho in YAG concentration and 7 W at 1.6% as well as a Thulium fiber laser pumped Cr:ZnSe thin disk cw laser with an output power of 0.4 W will be presented. Comparison of the output power to a Rigrod formula with Boltzmann occupation factors will be shown.

### Introduction

Holmium- or Chromium-doped crystals emit in the 2  $\mu\text{m}$  'eye-safe' wavelength range and are therefore attractive for use in remote sensing, laser material processing as well as laser surgery or therapy [1]. In the present report a single mode Thulium fiber laser at 1.908  $\mu\text{m}$  will be used to pump a Ho:YAG thin disk laser [2] with two different Ho concentrations in a multi-pass pumping scheme via a multimode transfer fiber to generate a flat pump intensity distribution on the disk. With a 24 pump pass concept an efficient absorption of the pump light in the Ho:YAG disk material will be achieved. Furthermore, the same multi-pass pumping concept will be used to pump a Cr:ZnSe thin disk cw laser [3], but in this case, directly with the single mode Thulium fiber laser.

### Experimental results of the Ho:YAG and Cr:ZnSe thin disk cw lasers

The single mode Tm fiber laser (IPG, 50 W) is focussed into a 600/660  $\mu\text{m}$  polyimide transfer fiber before entering the Ho:YAG disk laser module (Dausinger + Giesen GmbH) [4, 5]. The Ho concentration of disk 1 is 2% (thickness of 500  $\mu\text{m}$ ). The disk 2 has a 1.6% Ho concentration (thickness of 500  $\mu\text{m}$ ). The pump beam spot size for the Ho:YAG disk is adjusted to a diameter of approximately 2 mm. The transmission of the output mirror has been changed between 1 and 5%. The output power of the Ho:YAG thin disk cw laser is shown in figure 1 for a optimized output transmission between 2 and 3%. For a pump power of 47 W the output power reached 15 W with a maximum efficiency of 37%. It can be recognized that the output power still shows a linear power scaling dependence in contrast to the 1.4% Ho concentration disk.

For the Cr:ZnSe thin disk cw laser with a disk thickness of 250  $\mu\text{m}$  the pump spot size has to be reduced to 0.75 mm to reach threshold. An output power of 0.4 W with an emission close to 2.35  $\mu\text{m}$  and a linewidth of 30 nm has been accomplished so far.

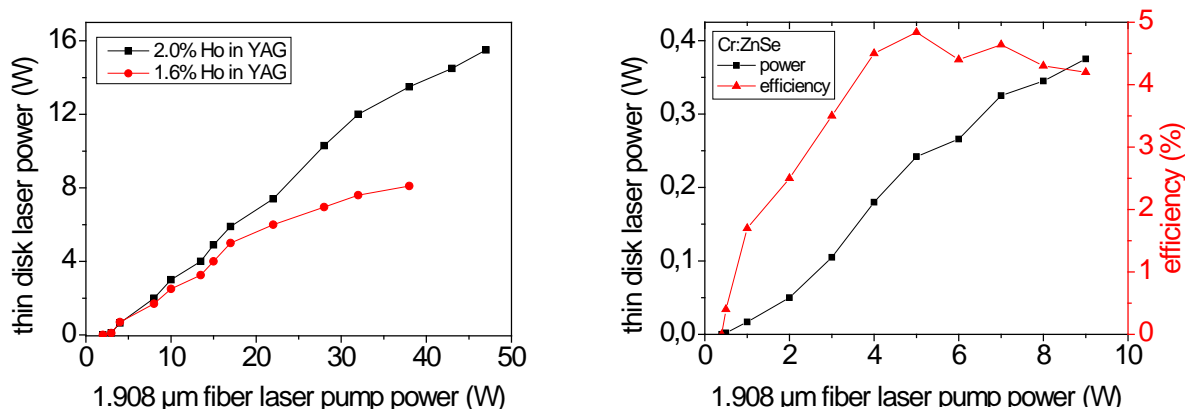


Fig 1. Output power of Ho:YAG ( left) and Cr:ZnSe (right) thin disk cw laser versus pump power

## Simplified Rigrod simulation for the Ho:YAG system

For the Ho<sup>3+</sup>-ions only two transitions in the two <sup>5</sup>I<sub>7</sub> and <sup>5</sup>I<sub>8</sub> manifolds are necessary to describe the absorption and amplification processes. With the Boltzmann occupation factors of the involved Ho<sup>3+</sup>-Stark levels and the reflection coefficients R of the crystal facets, the laser output intensity normalized to the saturation intensity will be calculated for a disk with a relatively large thickness [6]:

$$I_{laser} = (1 - R_s^l) \cdot \sqrt{R_m^l} \cdot \frac{g_o \cdot (\alpha_o^{-1} \cdot I_p^+(0) \cdot (1 - \Gamma) \cdot (1 + R_m^p \cdot \Gamma) - f_1 \cdot L) + \ln \sqrt{R_m^l \cdot R_s^l}}{(1 - \sqrt{R_m^l \cdot R_s^l}) \cdot (\sqrt{R_m^l} + \sqrt{R_s^l})}; \quad \Gamma = (R_m^l \cdot R_s^l)^{\alpha_o/2g_o} \cdot \exp(-\alpha_o \cdot (f_2 - f_1) \cdot L) \quad (1)$$

The Boltzmann population factors for the Ho<sup>3+</sup>-laser and pump levels are taken from the literature:  $f_a = 0.154$ ,  $f_l = 0.017$ ,  $f_u = 0.0994$ ,  $f_b = 0.0994$  [7] with  $f_1 = f_a/(f_a + f_b)$ ,  $f_2 = f_l/(f_l + f_u)$ . The gain and absorption can be calculated from the products of the cross-sections (eff. pump absorption  $5 \cdot 10^{-21} \text{ cm}^2$ , eff. stimulated emission  $12 \cdot 10^{-21} \text{ cm}^2$ ), the Ho in YAG concentration and the Boltzmann factors. The 2% Ho concentration is set to  $3 \cdot 10^{20} \text{ cm}^{-3}$ . In figure 2 the laser output intensity is depicted for the 2% and 1.6% Ho concentration with  $I_p(0) = 1$  and a disk thickness of  $L = 400 \text{ }\mu\text{m}$ . For the 2% of Ho concentration case the experimental laser intensity of  $0.5 \text{ kW/cm}^2$  (power 15 W, beam diameter 2 mm) is shown in figure 2, too.

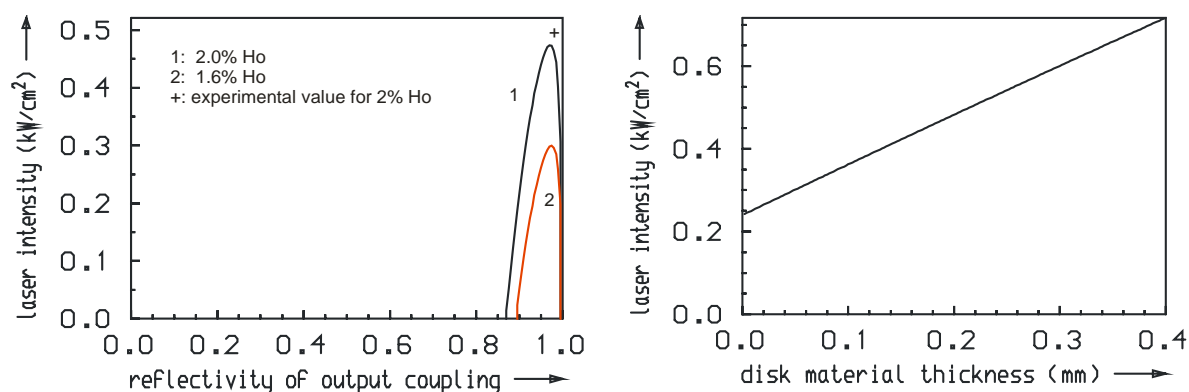


Fig 2. Simulation of laser intensity versus reflectivity of output coupling coefficient (left diagram) for 2% and 1.6% Ho in YAG concentrations and laser intensity versus disk thickness (right diagram) for the 2% Ho in YAG concentration and a 2% output coupling coefficient

## Conclusions

Holmium doped YAG and Chromium doped ZnSe are promising laser materials for thin disk laser concepts in the 2  $\mu\text{m}$  range. A cw laser output power of 15 W has been achieved with an efficiency of 37% for a Ho in YAG concentration of 2% with scaling opportunities to higher power. For the Cr:ZnSe thin disk cw laser an output power of 0.4 W at 2.35  $\mu\text{m}$  has been realized so far.

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